· MA: DDR3-1866 (933MHz @ CL=13, tRCD=13, tRP=13) · NB: DDR3-2133 (1066MHz @ CL=14, tRCD=14,

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tRP=14)







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### **PRODUCTS**

#### DRAM

- Server DRAM

- PC DRAM

- Mobile DRAM

<sup>-</sup> Consumer DRAM

- Graphic DRAM

Flash Storage

- V-NAND Technology

- Client SSD

- Enterprise SSD

- eMMC

- UFS

- eMMC Based MCP

- ePoP

About Us

News

## **Exynos Solution**

- Application Processor

- ModAP

- Modem/RF

ISOCELL Image Sensor

- Mobile CIS

- Industry CIS

Display Solution

- Mobile DDI

- Panel DDI/TCON

Touch Controller

Security Solution - Smart Card

Power IC

Bio-Processor

#### **APPLICATION**

#### Data Center

- Web Server

- Application Server

- DB Server

- Storage Server

Mobile Device

- Smartphone

- Wearable

Consumer Device

- Desktop

- Notebook

- Smart TV

- Game Console

By Industry

- Industrial

- Banking/ID

- Healthcare & Wellness

# **FOUNDRY**

**About Samsung Foundry** 

Manufacturing

Process Technology

- 32/28nm

Service

- Design Solution - MPW Shuttle Service

- Mask Service

- Back-end Service

- E-service

# **MORE SITES**

LED ☐

Worker Safety **△** 

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